



40V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D T _C = +25°C (Note 10)
40V	$3.3 \text{m}\Omega @ V_{GS} = 10V$	100A
407	$5.0 \text{m}\Omega @ V_{GS} = 5V$	95A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

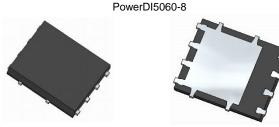
- **BLDC Motors**
- DC-DC Converters
- Load Switch

Features

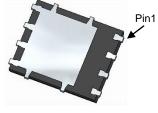
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable And Robust End Application
- Low R_{DS(ON)} Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: PowerDI®5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)

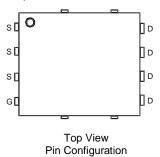


Top View



Bottom View

Internal Schematic



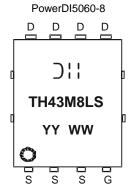
Ordering Information (Note 5)

Part Number	Case	Packaging
DMTH43M8LPSQ-13	PowerDI5060-8	2,500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/product-compliance-definitions/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



☐ I = Manufacturer's Marking TH43M8LS = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 17 = 2017) WW = Week Code (01 to 53)



Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V_{DSS}	40	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current, V _{GS} = 10V (Note 6)	$T_A = +25^{\circ}C$ $T_A = +100^{\circ}C$	I _D	22 15.5	А
Continuous Drain Current, V _{GS} = 10V (Note 7) (Note10)	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	I _D	100 82	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	350	Α	
Maximum Continuous Body Diode Forward Current (Note 7)	Is	69	А	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		I _{SM}	350	Α
Avalanche Current, L = 1mH		I _{AS}	13.2	Α
Avalanche Energy, L = 1mH		E _{AS}	87	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	$T_A = +25$ °C	P _D	2.7	W
Thermal Resistance, Junction to Ambient (Note 6)		$R_{\theta JA}$	55	°C/W
Total Power Dissipation (Note 7)	T _C = +25°C	P _D	83	W
Thermal Resistance, Junction to Case (Note 7)		R _{0JC}	1.8	°C/W
Operating and Storage Temperature Range		$T_{J_{i}}T_{STG}$	-55 to +175	°C

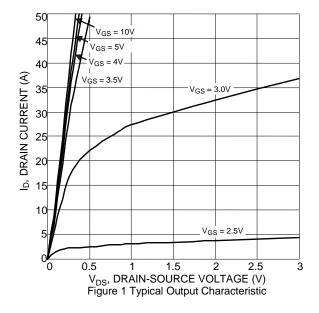
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

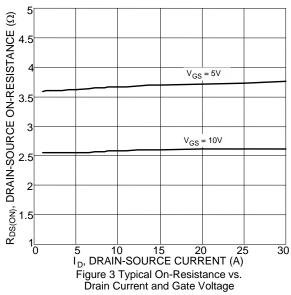
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	40	_	_	V	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	$V_{DS} = 32V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	1		2.5	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Statio Drain Source On Begintance (T. 125°C)		_	2.7	3.3	0	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance (T _C = +25°C)	R _{DS(ON)}	_	3.6	5.0	mΩ	$V_{GS} = 5V, I_D = 15A$	
Static Drain-Source On-Resistance (T _C = +175°C) (Note 9)	R _{DS(ON)}	1	4.7	_	mΩ	$V_{GS} = 10V, I_D = 20A$	
Diode Forward Voltage	V_{SD}			1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{ISS}	_	2,693	3,367		V _{DS} = 20V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss	_	850	1105	pF		
Reverse Transfer Capacitance	C _{RSS}	_	52	104			
Gate Resistance	R_G	_	2.54	5.1	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 10V)	Q_{G}	_	38.5	49		V _{DS} = 20V, I _D = 20A	
Total Gate Charge (V _{GS} = 4.5V)	Q_{G}	_	17.6	22	nC		
Gate-Source Charge	Q _{GS}	_	6.9	11	nc nc		
Gate-Drain Charge	Q_{GD}	_	6.9	11			
Turn-On Delay Time	t _{D(ON)}	_	5.2	10		$V_{DD} = 20V, V_{GS} = 10V,$ $I_{D} = 20A, R_{G} = 1.6\Omega$	
Turn-On Rise Time	t _R	_	5.7	11	20		
Turn-Off Delay Time	t _{D(OFF)}	_	23.5	46	ns		
Turn-Off Fall Time	t _F	_	11	22			
Body Diode Reverse Recovery Time	t _{RR}	_	35.4	70	$\frac{\text{ns}}{\text{nC}}$ I _F = 15A, di/dt = 100A/µs		
Body Diode Reverse Recovery Charge	Q _{RR}	_	32.9	_			

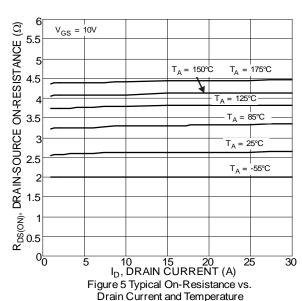
Notes:

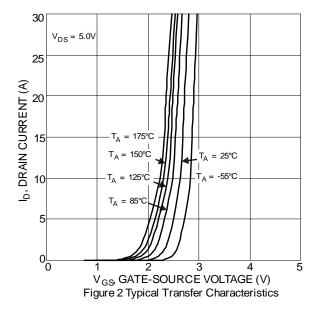
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
- 7. Thermal resistance from junction to soldering point (on the exposed drain pad).
- Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.
- 10. Package limit.

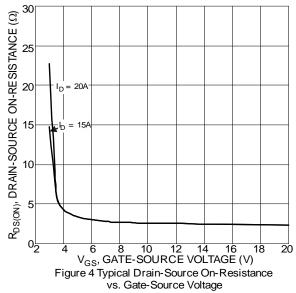












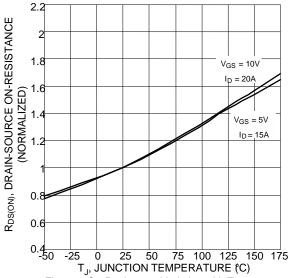


Figure 6 On-Resistance Variation with Temperature





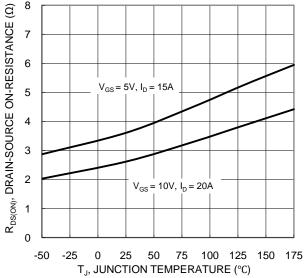
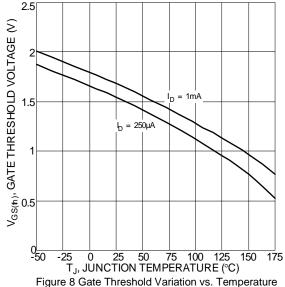
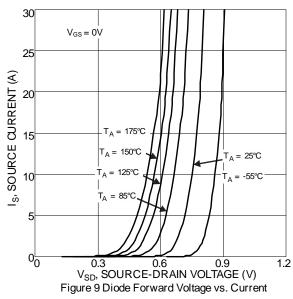
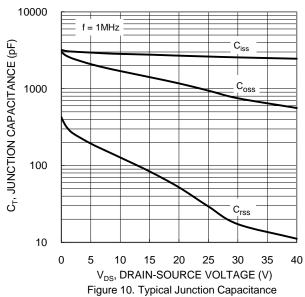


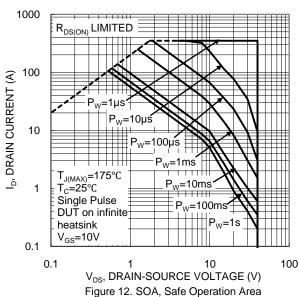
Figure 7. On-Resistance Variation with Temperature



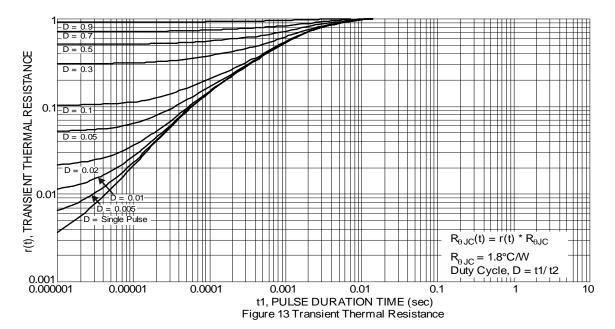


 $V_{GS}(V)$ $V_{DS} = 20V, I_{D} = 20A$ Qg (nC) Figure 11. Gate Charge







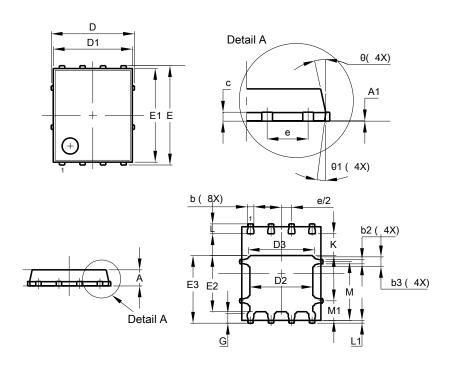




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

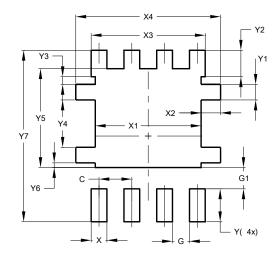


PowerDI5060-8					
Dim	Min	Тур			
Α	0.90	1.10	1.00		
A1	0.00	0.05	_		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
C	0.230	0.330	0.277		
D	5.15 BSC				
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
Е	(6.15 BSC	;		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	_	_		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
M	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
Х	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Υ	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



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